**Vishay Semiconductors** 

# Ultrafast Rectifier, 30 A FRED Pt®



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SHA)

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 30 A						
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.15 V					
t <sub>rr</sub> (typ.)	30 ns					
T <sub>J</sub> max.	175 °C					
Package	TO-220AC 2L					
Circuit configuration	Single					

#### **FEATURES**

- · Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- · Low leakage current
- True 2 pin package
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

Ultralow V<sub>F</sub>, soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V				
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 130 °C	30	٨				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	200	A				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.4	2.0	V		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.15	1.35			
		$V_{\rm R} = V_{\rm R}$ rated	-	0.02	30			
Reverse leakage current I <sub>R</sub>		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	250	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	_	8	-	nH		

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \ dI_F/dt = 50 \text{ A}$	= = 1 A, dI <sub>F</sub> /dt = 50 A/µs, V <sub>R</sub> = 30 V			45			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	45	-	ns		
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 30 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>B</sub> = 200 V	-	100	-			
Deals receivers a unreat		T <sub>J</sub> = 25 °C		-	5.6	-	A		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	10	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	127	-	nC		
		T <sub>J</sub> = 125 °C		-	580	-	nc		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	0.84	1.3			
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W		
Typical thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-220AC 2L	ETU3006					

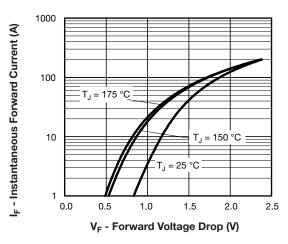


Fig. 1 - Typical Forward Voltage Drop Characteristics

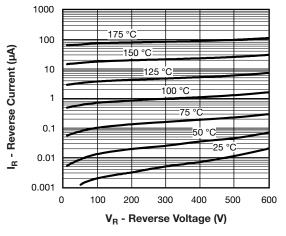


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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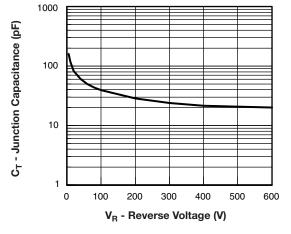


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

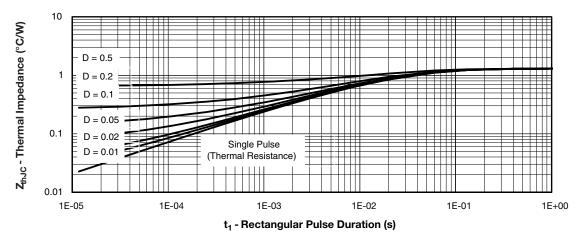
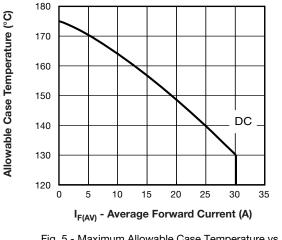
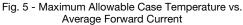
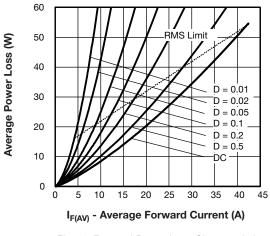
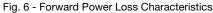


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics









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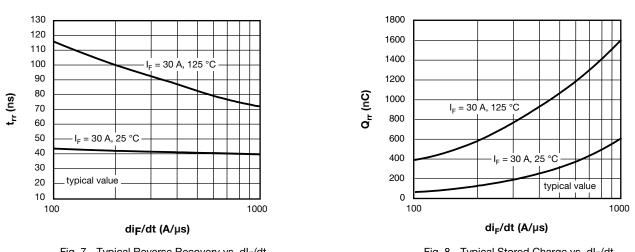
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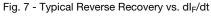
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Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

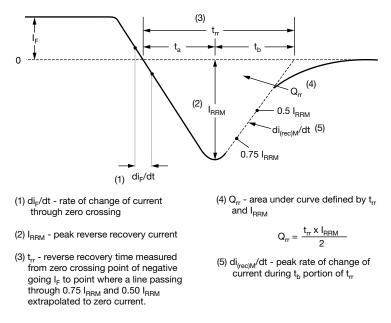


Fig. 9 - Reverse Recovery Waveform and Definitions

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#### **ORDERING INFORMATION TABLE**

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Device code	VS-	E	Т	U	30	06	-M3
		I					
	(1)	(2)	(3)	$\begin{pmatrix} 1 \\ 4 \end{pmatrix}$	(5)	(6)	(7)
		$\cup$	Ŭ	Ŭ	Ŭ	U	Ŭ
	1	- Visł	nay Sem	niconduo	ctors pr	oduct	
	2	- Circ	cuit cont	figuratio	n:		
		E =	single				
	3	- T=	2L TO-2	220AC			
	<b>4</b>	- U =	hyperfa	ast recov	very tim	е	
	5	- Cur	rent coo	de: 30 =	30 A		
	6	- Voli	tage coo	de: 06 =	600 V		
	7	- Env	ironmer	ntal digit			
		-M3	3 = halos	gen-free	, RoHS	-compli	iant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-ETU3006-M3	50	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96156						
Part marking information	www.vishay.com/doc?95391					
SPICE model	www.vishay.com/doc?96436					

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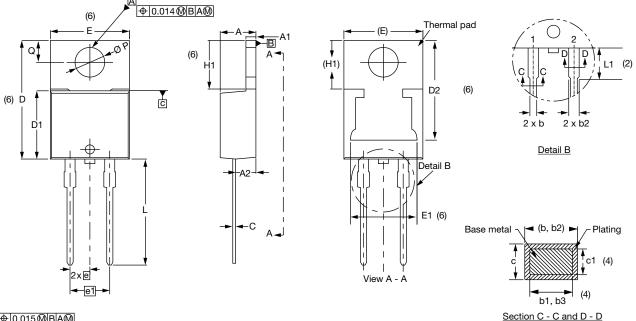
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### **TO-220AC 2L**

#### **DIMENSIONS** in millimeters and inches

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⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC<sup>®</sup> outline TO-220AC

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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